



20V N-Channel Enhancement Mode MOSFET

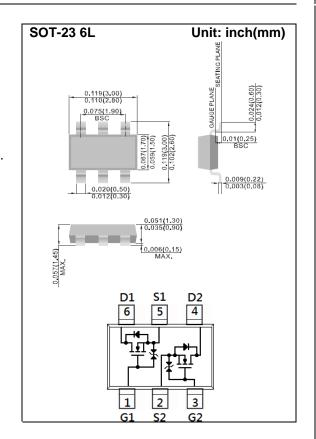
Voltage 20 V Current 750mA

Features

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams
- Marking: SG4



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	<u>+</u> 10	V
Continuous Drain Current		I _D	750	mA
Pulsed Drain Current (Note 4)		I _{DM}	1500	mA
Power Dissipation	T _a =25°C	P _D	500	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250uA$	0.3	0.65	0.9	V
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =4.5V, I_{D} =600mA	-	280	400	mΩ
		V _{GS} =2.5V, I _D =200mA	-	350	650	
		V _{GS} =1.8V, I _D =100mA	-	400	800	
		V_{GS} =1.5V, I_{D} =50mA	-	500	1200	
		V_{GS} =1.2V, I_{D} =20mA	-	1000	3000	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} =16V, V_{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\underline{+}8V, V_{DS}=0V$	-	<u>+</u> 0.5	<u>+</u> 10	uA
Dynamic ^(Note 5)						
Total Gate Charge	Q_g	V _{DS} =10V, I _D =600mA, V _{GS} =4.5V ^(Note 1,2)	-	1.4	-	nC
Gate-Source Charge	Q_gs		-	0.22	-	
Gate-Drain Charge	Q_gd		-	0.21	-	
Input Capacitance	Ciss	.,	-	67	-	pF
Output Capacitance	Coss	V_{DS} =10V, V_{GS} =0V, f =1.0MHZ	-	19	-	
Reverse Transfer Capacitance	Crss	I=1.0IVII IZ	-	6	-	
Turn-On Delay Time	td _(on)	\/ 40\/ I 450m \	-	2.8	-	
Turn-On Rise Time	tr	V_{DD} =10V, I_{D} =150mA, V_{GS} =4.0V, R_{G} =10 Ω (Note 1.2)	-	20	-	ns
Turn-Off Delay Time	td _(off)		-	23	-	
Turn-Off Fall Time	tf	K _G =1002	-	23	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S		-	-	500	mA
Diode Forward Voltage	V_{SD}	I _S =500mA, V _{GS} =0V	_	0.87	1.3	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

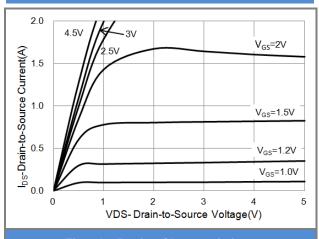


Fig.1 On-Region Characteristics

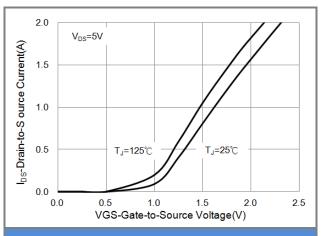


Fig.2 Transfer Characteristics

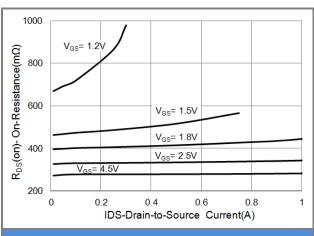


Fig.3 On-Resistance vs. Drain Current

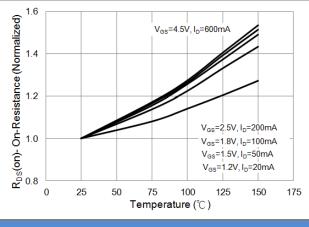
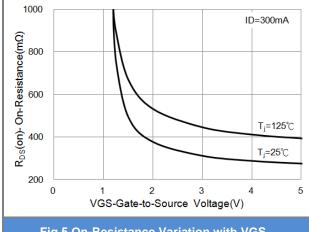


Fig.4 On-Resistance vs. Junction temperature





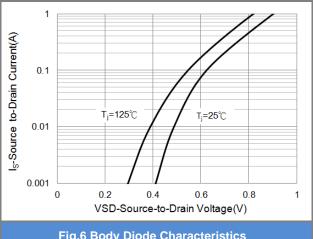


Fig.6 Body Diode Characteristics





TYPICAL CHARACTERISTIC CURVES

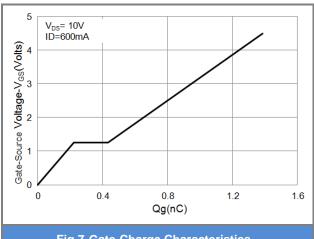


Fig.7 Gate-Charge Characteristics

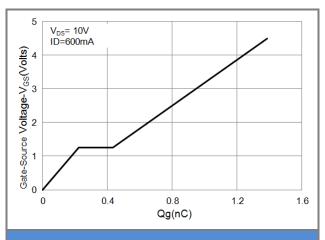


Fig.8 Threshold Voltage Variation with Temperature.

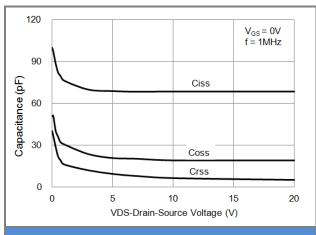


Fig.9 Capacitance vs. Drain-Source Voltage.

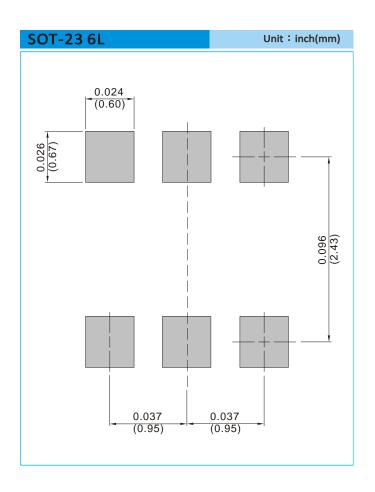




PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJS6834_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG4	Halogen free
PJS6834_S2_00001	SOT-23 6L	10K pcs / 13" reel	SG4	Halogen free

MOUNTING PAD LAYOUT







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